



Solid State Devices, Inc.

14701 Firestone Blvd * La Mirada, CA 90638
Phone: (562) 404-4474 * Fax: (562) 404-1773
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Designer's Data Sheet

Part Number/Ordering Information ^{1/}

SDA475- 02 S

L Screening ^{2/}

— = Not Screened
TX = TX Level
TXV = TXV Level
S = S Level

Voltage

02 = 18,000 Volts

SDA475-02

3 AMP / 18,000 VOLTS HIGH VOLTAGE MULTIPLIER RECTIFIER STACK

FEATURES:

- Aerospace high voltage power supply applications
- High blocking voltage: 18 kV minimum
- Low mechanical stress design
- Excellent thermal management: 2.5°C/W
- TX, TXV, and S-level screening available^{2/}
- Consult factory for:
 - Higher blocking voltages
 - Faster switching speeds
 - Other electrical configurations

MAXIMUM RATINGS ^{3/}

	SYMBOL	VALUE	UNIT
Peak Repetitive Reverse and DC Blocking Voltage Each rectifier	V_{RM} V_{RWM} V_R	6,000	Volts
Average Rectified Forward Current Non-repetitive, t = 8.3 ms pulse	I_O	3	Amps
Peak Surge Current Non-repetitive, t = 8.3 ms pulse, T _A = 25°C	I_{FSM}	25	Amps
Operating and Storage Temperature	T _{OP} & T _{STG}	-65 to +150	°C
Thermal Resistance, Junction to Base	Θ _{JB}	2.5	°C/W

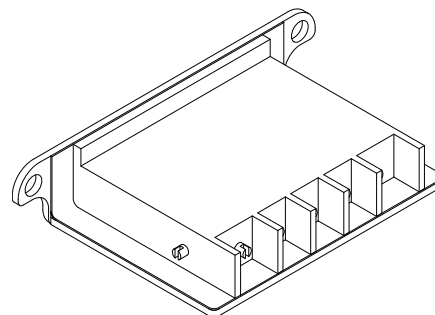
NOTES:

^{1/} For ordering information, price, operating curves, and availability- contact factory.

^{2/} Screening based on MIL-PRF-19500. Screening flows available on request.

^{3/} Unless otherwise specified, all electrical characteristics @ 25°C.

ASPM



NOTE: All specifications are subject to change without notification.
SCD's for these devices should be reviewed by SSDI prior to release.

DATA SHEET #: PM0005B

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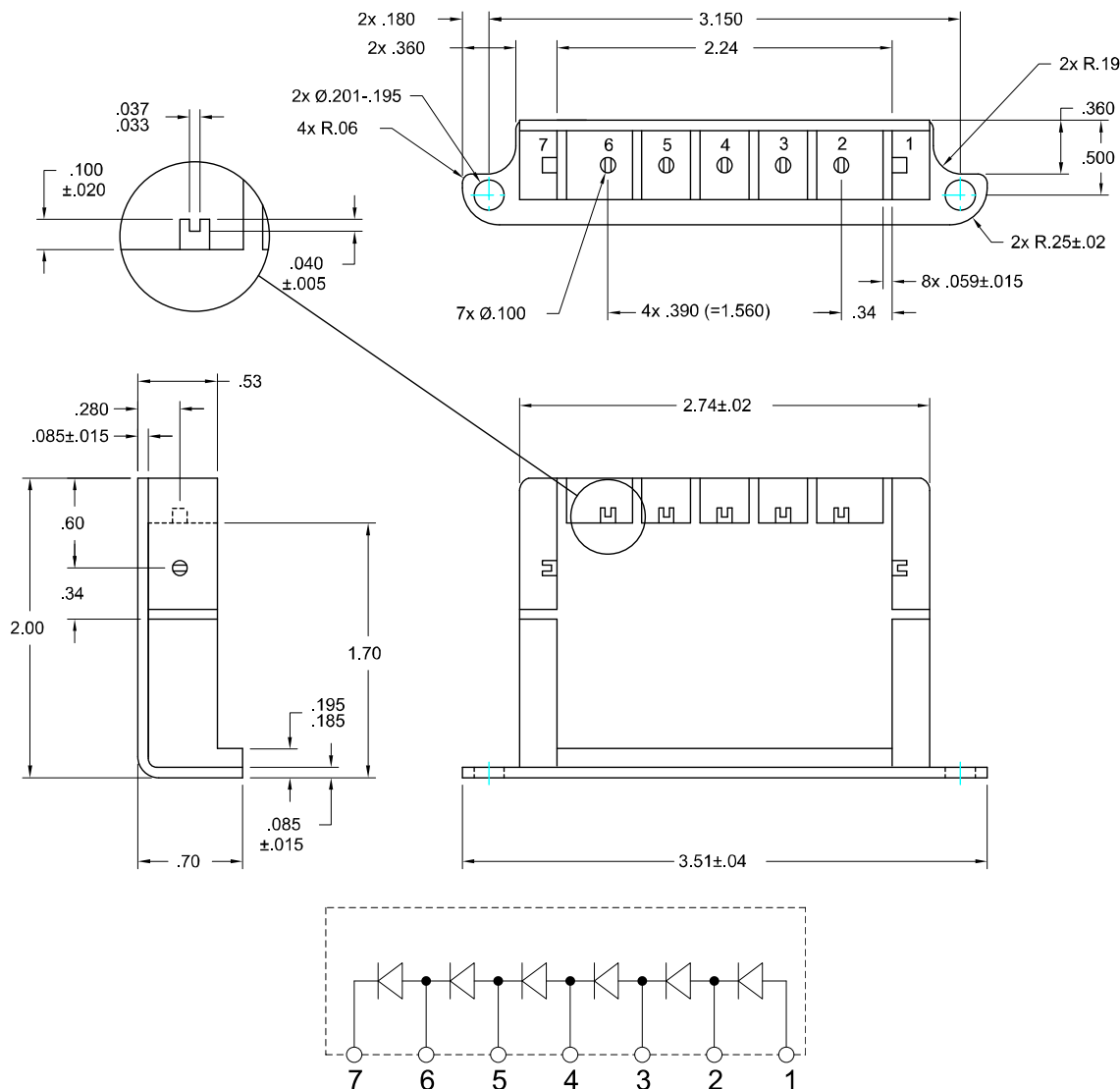
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SDA475-02

ELECTRICAL CHARACTERISTICS (Each rectifier)^{3/}

PARAMETER	SYMBOL	MIN	MAX	UNIT
Instantaneous Forward Voltage Drop $I_F = 0.6A$	V_F	--	10	Volts
Reverse Leakage $V_R = 6,000V$	I_{R1} I_{R2}	-- --	2 200	μA
Insulation Resistance All terminals to base @15,000V	R_{INSUL1}	10	-	$G\Omega$
Reverse Recovery Time $I_F = 0.5A$, $I_R = 1.0A$, $I_{RR} = 0.25A$	t_{RR}	--	70	nsec

Package Outlines: ASPM



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